

Temperature control system for diamond characterization using ion beams

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Collaborators:



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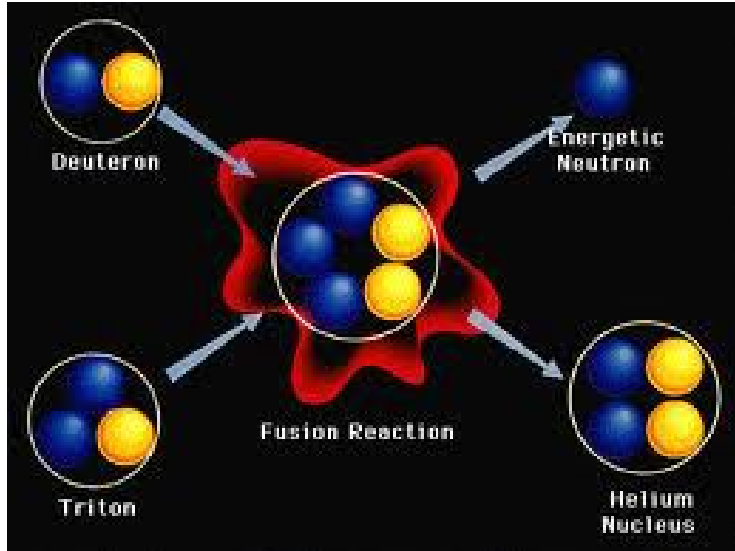
W. Kada



Outline

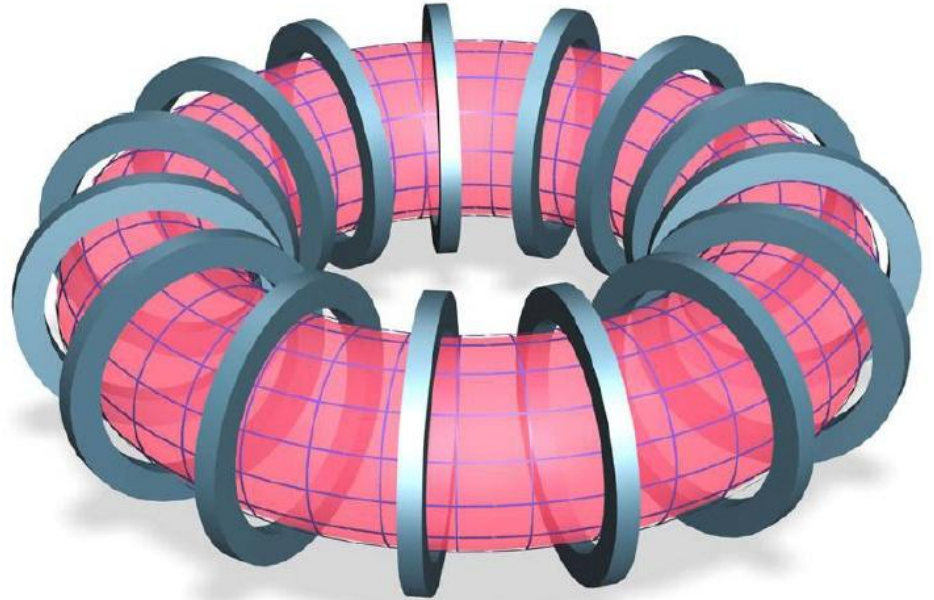
- Fusion - future power plants
- Design of temperature control system
- Using the system:
 - Ion Beam Induced Charge
 - Charge Transient Spectroscopy

Fusion on Earth



150 million degrees

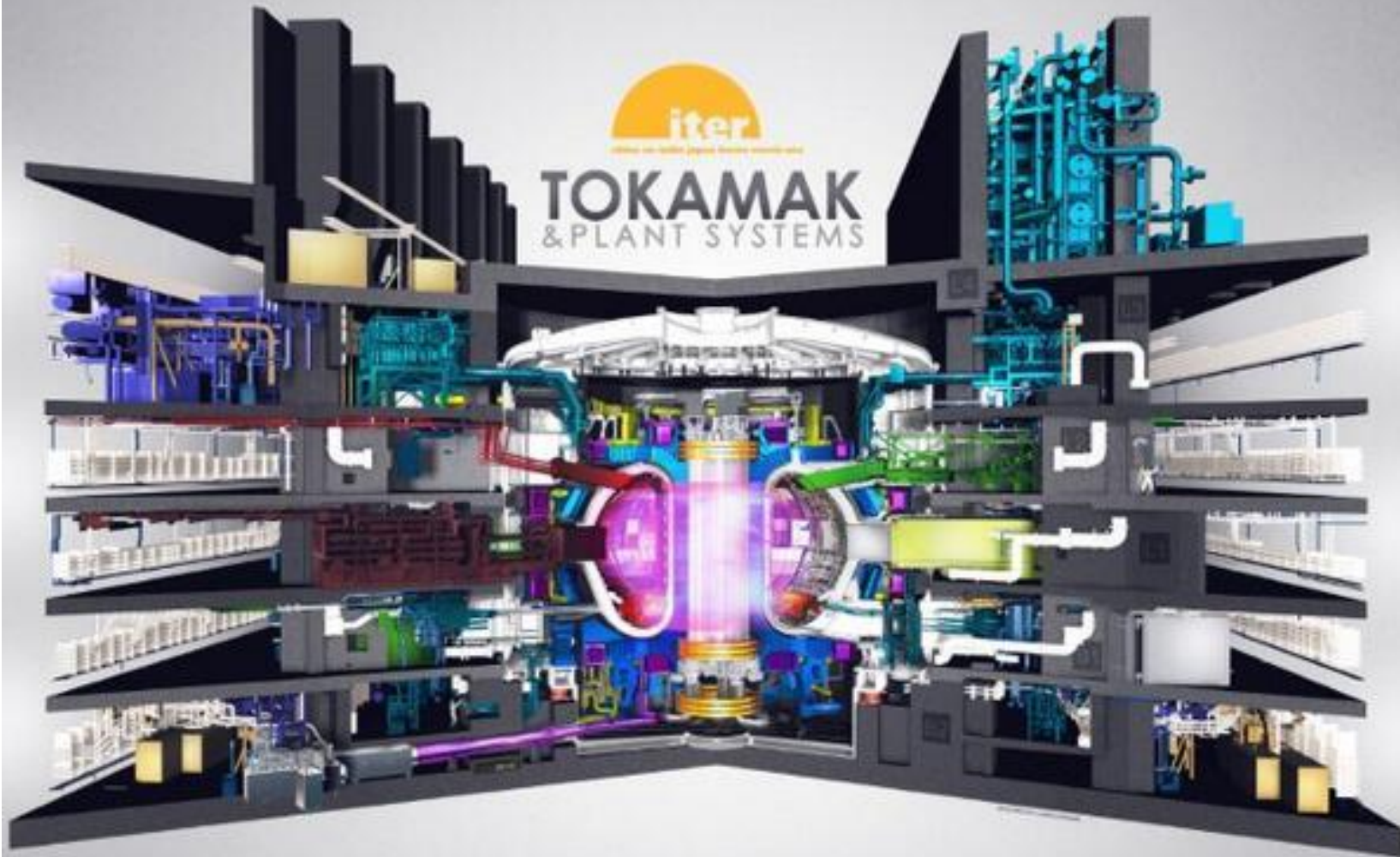
TOKAMAK



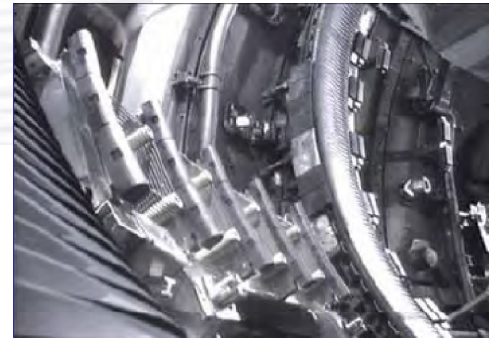
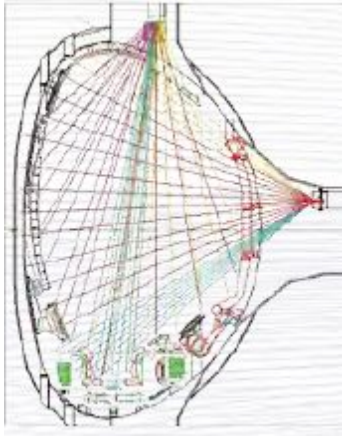
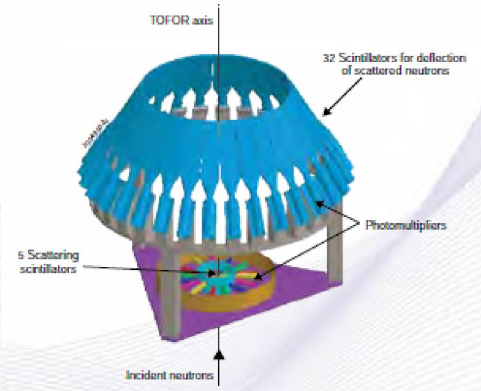
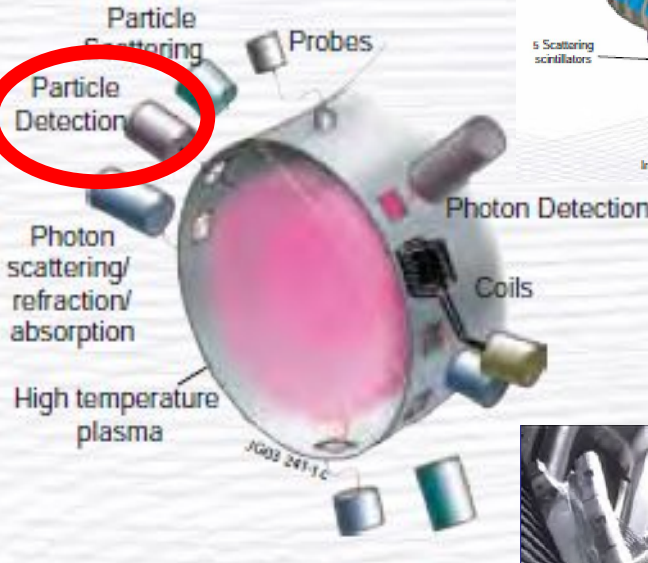


international thermonuclear experimental reactor

TOKAMAK & PLANT SYSTEMS



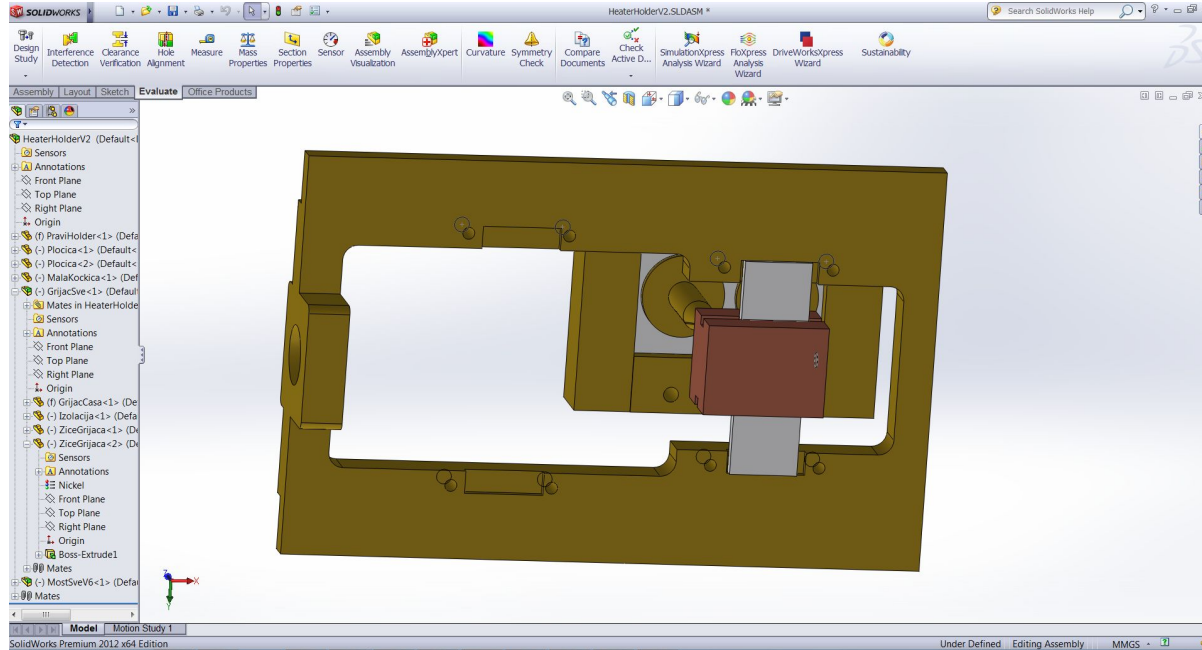
Plasma Diagnostics



Task

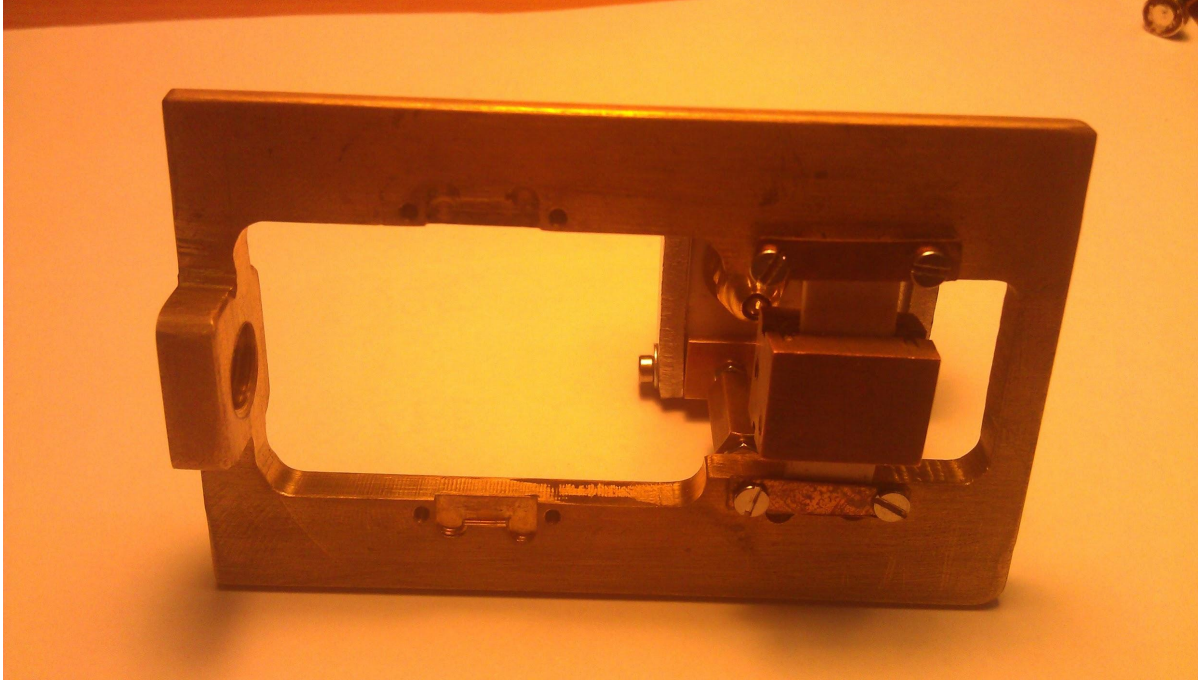
- How to test particle detectors on different temperatures?
- Design and construct a system for sample characterization using ion beams in the temperature range of -100 °C to +600 °C.

Mechanical design and manufacturing



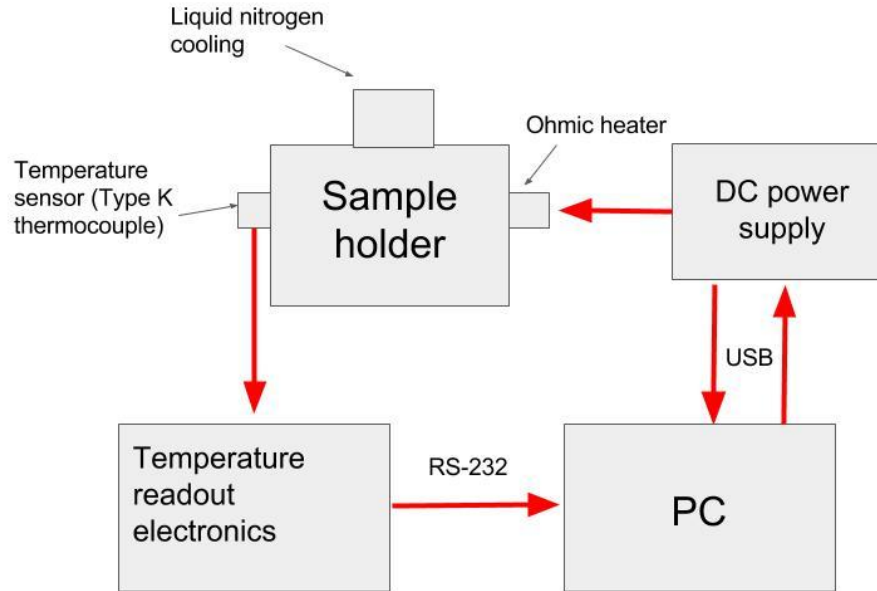
- 3D CAD model using Solidworks

Mechanical design and manufacturing



- In house manufacturing

Computer controlled heating and cooling:

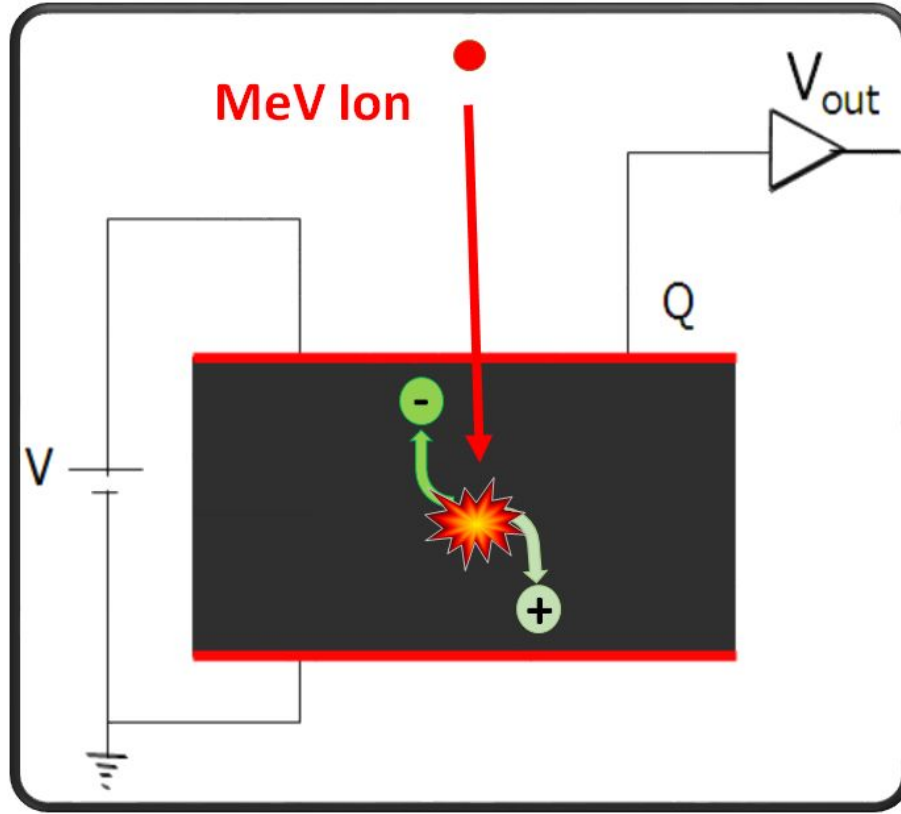


- Homemade python temperature control software

Tested capabilities

- Temperature range: -120 °C to +650 °C
- Temperature stability: better than ± 0.5 °C (for heating part)
- Vacuum level after heating: better than 10^{-5} mbar
- Chamber temperature: less than 50°C
- Electromagnetic noise: not seen in electrical measurements

Charge generation and collection



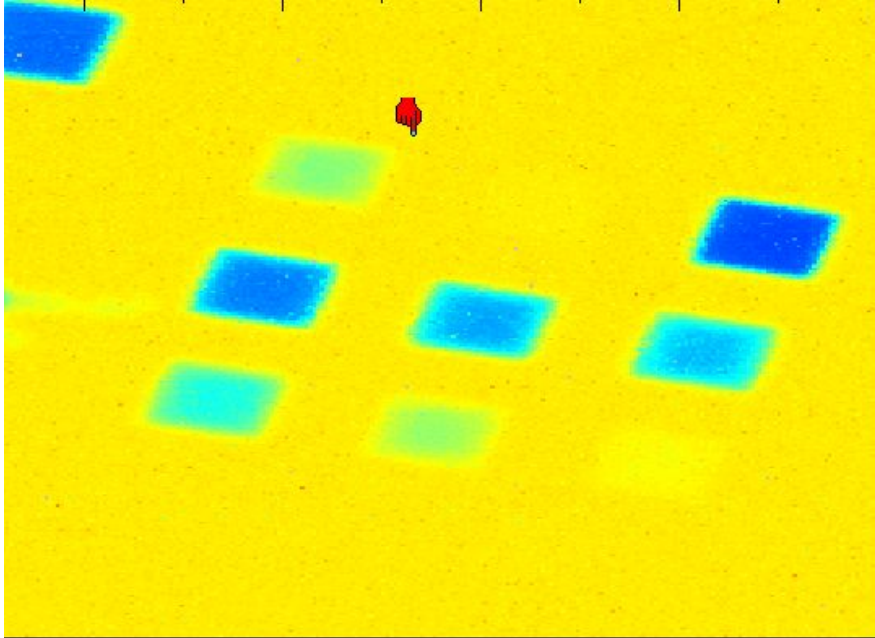
Collecting total charge

- 50 μm thick scCVD diamond detector from DDL

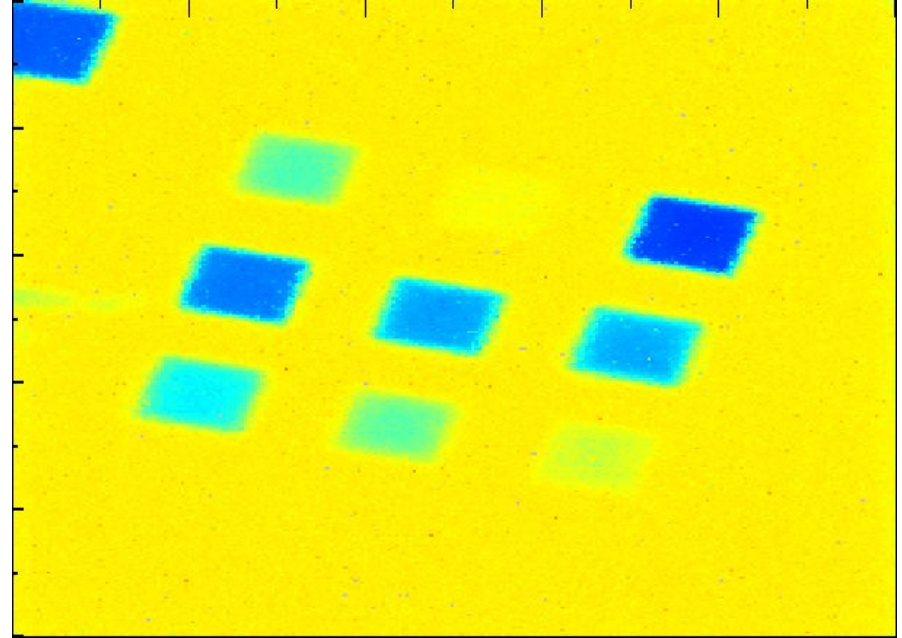


Ion Beam Induced Charge

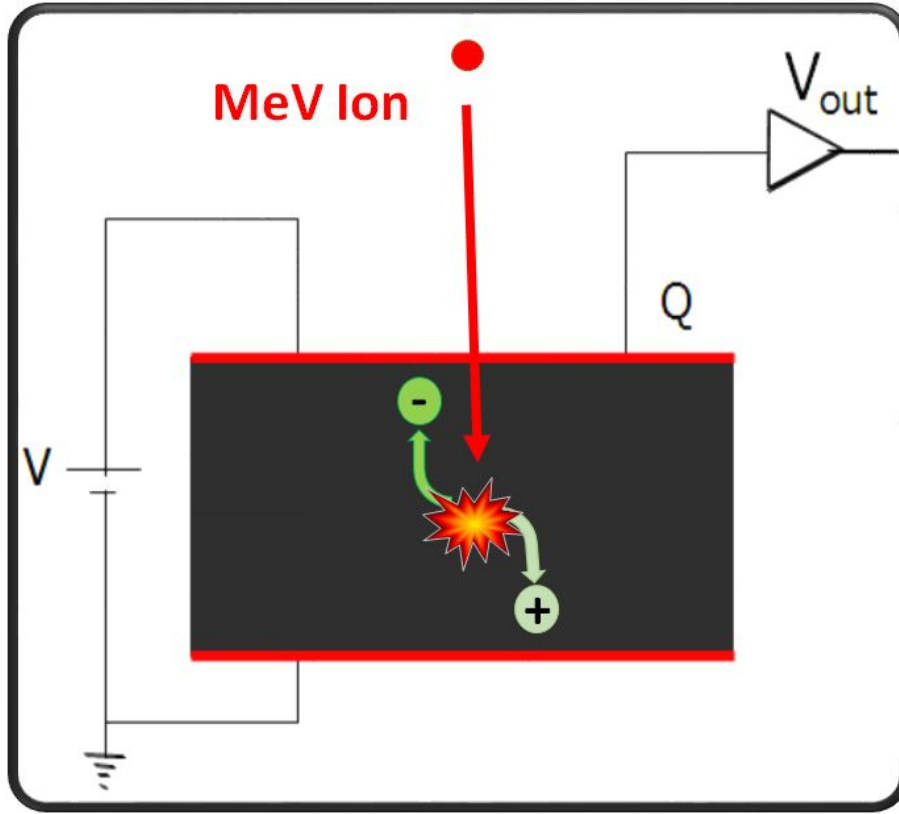
25 °C



250 °C



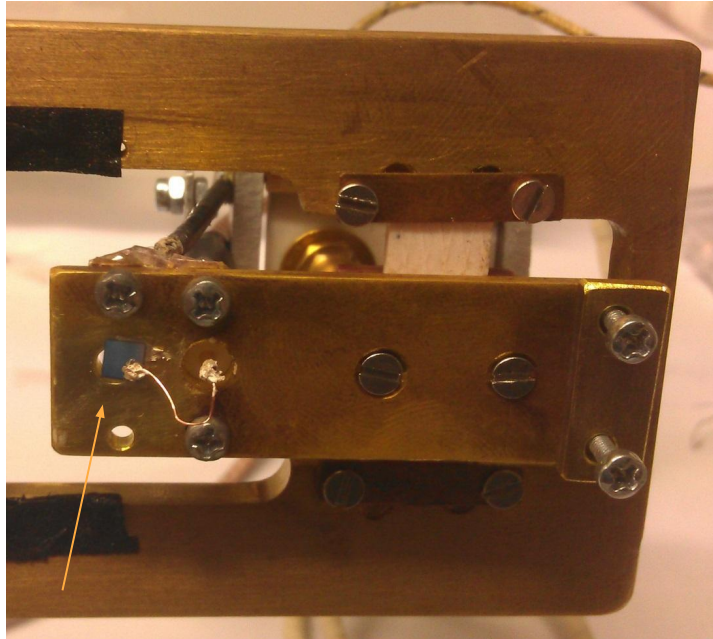
Charge generation and collection



Measuring transient current

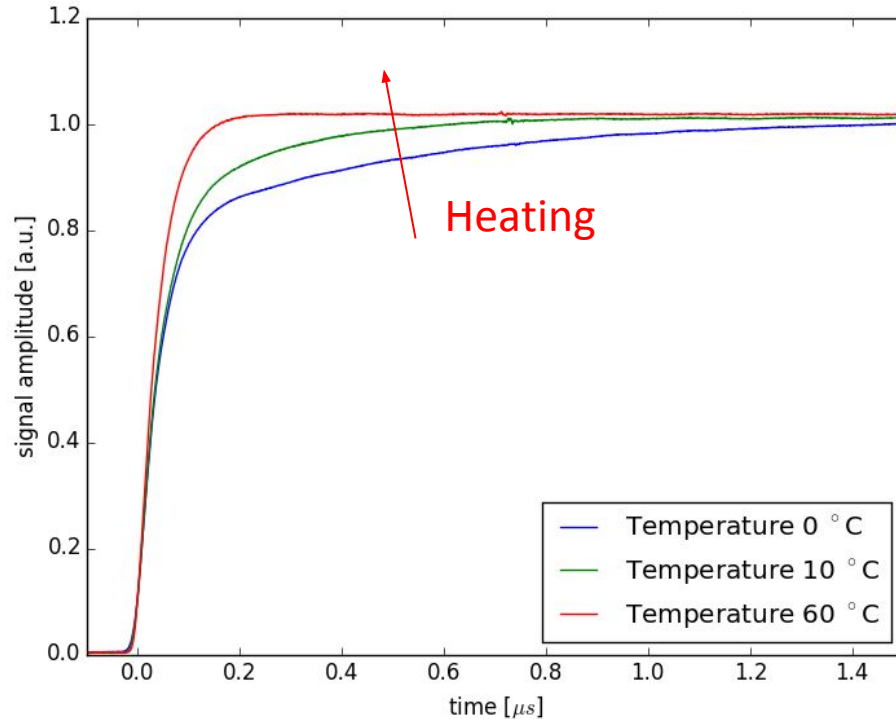
Charge transient spectroscopy (QTS) setup

- CoolFET preamplifier
- WaveMaster 8500A oscilloscope



NDT sample mounted on QTS setup

QTS trace analysis



$$A = A_0(1 - e^{-e_1 t})$$

$$e_1 \sim \sigma N_D e^{-\frac{\Delta E}{kT}}$$

- Traps in whole sample:
 - $\Delta E = 0.53 \text{ eV} \pm 0.1 \text{ eV}$
 - σN_D is lower
 - Boron? Arsenic?
- Traps close to the edge:
 - $\Delta E = 0.43 \text{ eV} \pm 0.04 \text{ eV}$
 - σN_D is higher
 - Boron? Arsenic?

Future plans

- Higher temperature electrical measurements
 - Different material for contacts (Tungsten...)
 - Mechanical connections instead of soldering
- Irradiation damage on high temperature

Thank you for your attention!